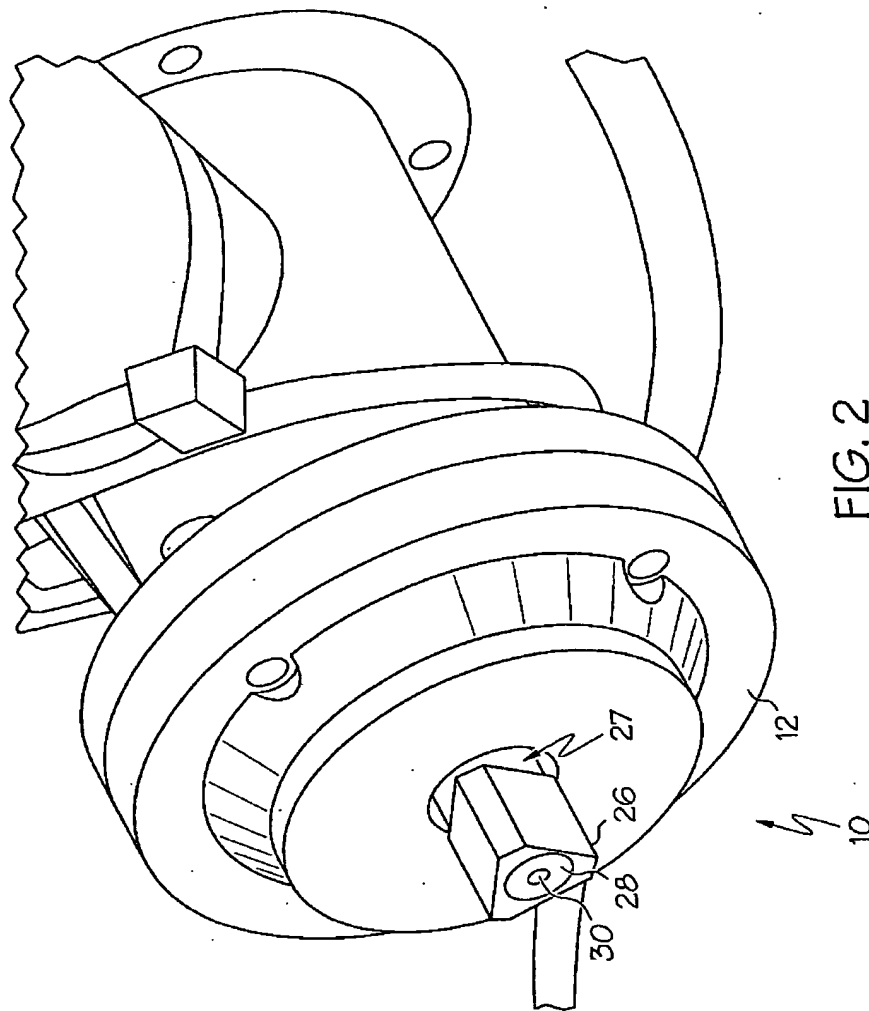


Application No.: 10/767,985
Reply to Office Action of January 9, 2006
Replacement Sheet

216

BEST AVAILABLE COPY



3 / 6

A detailed cross-sectional view of a multi-layered structure, likely a semiconductor device or a composite material. The structure is divided into several layers and regions, each labeled with a number. The top layer is labeled 14, with a downward arrow indicating a direction. Below it is a layer labeled 5, which contains a hatched region labeled 10. To the right of the hatched region is a rectangular block labeled 20. Below the 5 layer is a layer labeled 22, which contains a hatched region labeled 36. To the right of the hatched region is a rectangular block labeled 34. Below the 22 layer is a layer labeled 25, which contains a hatched region labeled 35. To the right of the hatched region is a rectangular block labeled 32. Below the 25 layer is a layer labeled 30, which contains a hatched region labeled 48. To the right of the hatched region is a rectangular block labeled 42. Below the 30 layer is a layer labeled 28, which contains a hatched region labeled 40. To the right of the hatched region is a rectangular block labeled 46. The bottom layer is labeled 26, which contains a hatched region labeled 44. To the right of the hatched region is a rectangular block labeled 40. The entire structure is shown in a cross-sectional view, with various layers and regions clearly defined by their labels and hatching patterns.

PAGE 22/23 * RCVD AT 3/30/2006 5:21:56 PM [Eastern Standard Time] * SVR:USPTO-EFXRF-8/43 * DNIS:2738300 * CSID:952 563 3009 * DURATION (mm-ss):07-30

Application No.: 10/767,985
Reply to Office Action of January 9, 2006
Replacement Sheet

4/6

BEST AVAILABLE COPY

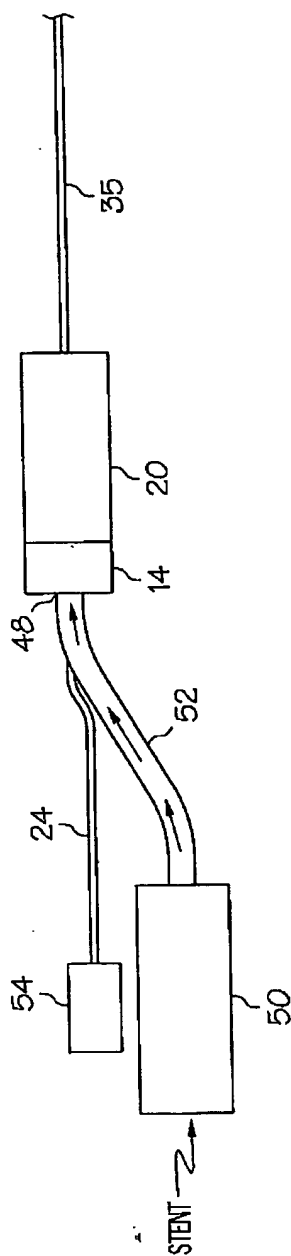


FIG. 4